

# UNISONIC TECHNOLOGIES CO., LTD

# UFZ34V

Preliminary

# 28A, 60V N-CHANNEL POWER MOSFET

# DESCRIPTION

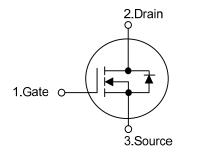
The UTC **UFZ34V** is an N-channel Power MOSFET, it uses UTC's advanced technology to provide the customers with a minimum on state resistance, high switching speed and low gate charge.

The UTC **UFZ34V** is suitable for all commercial-industrial applications, etc.

# FEATURES

- \*  $R_{DS(ON)}$  < 42m $\Omega$  @  $V_{GS}$ =10V,  $I_D$ =14A
- \* High switching speed
- \* Low gate charge

#### SYMBOL

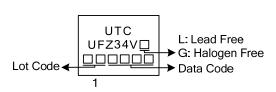


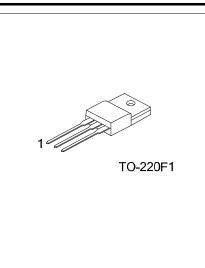
# ORDERING INFORMATION

Ordering Number		Daakaga	Pin Assignment			Docking
Lead Free	Halogen Free	Package	1	2	3	Packing
UFZ34VL-TF1-T	UFZ34VG-TF1-T	TO-220F1	G	D	S	Tube
Note: Pin Assignment: G: Gate D: Drain S: Source						

UFZ34V <u>L</u> - <u>TF1-T</u>	
(1)Packing Type	(1) T: Tube
(2)Package Type	(2) TF1: TO-220F1
(3)Green Package	(3) L: Lead Free, G: Halogen Free and Lead Free

#### MARKING





# ■ ABSOLUTE MAXIMUM RATINGS (T<sub>c</sub> =25°C, unless otherwise specified)

PARAMETER		SYMBOL	RATINGS	UNIT	
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
Drain Current	Continuous	I <sub>D</sub>	28	А	
	Pulsed (Note 2)	I <sub>DM</sub>	112	А	
Avalanche Energy	Single Pulsed (Note 3)	E <sub>AS</sub>	540	mJ	
Peak Diode Recovery dv/dt (Note 4)		dv/dt	20	V/ns	
Power Dissipation		PD	55	W	
Junction Temperature		TJ	+150	°C	
Storage Temperature Range		T <sub>STG</sub>	-55 ~ +150	°C	

Notes: 1. Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

2. Repetitive Rating : Pulse width limited by maximum junction temperature

3. L=120mH, I<sub>AS</sub>=3.0A, V<sub>DD</sub>= 50V, R<sub>G</sub>=25 $\Omega$ , Starting T<sub>J</sub>=25°C

4. I<sub>SD</sub> ≤28A, di/dt ≤200A/µs, V<sub>DD</sub> ≤BV<sub>DSS</sub>, Starting T<sub>J</sub>=25°C

# THERMAL DATA

PARAMETER	SYMBOL	RATING	UNIT	
Junction to Ambient	$\theta_{JA}$	62.5	°C/W	
Junction to Case	θ <sub>JC</sub>	2.27	°C/W	

#### ■ ELECTRICAL CHARACTERISTICS (T<sub>J</sub>=25°C, unless otherwise specified)

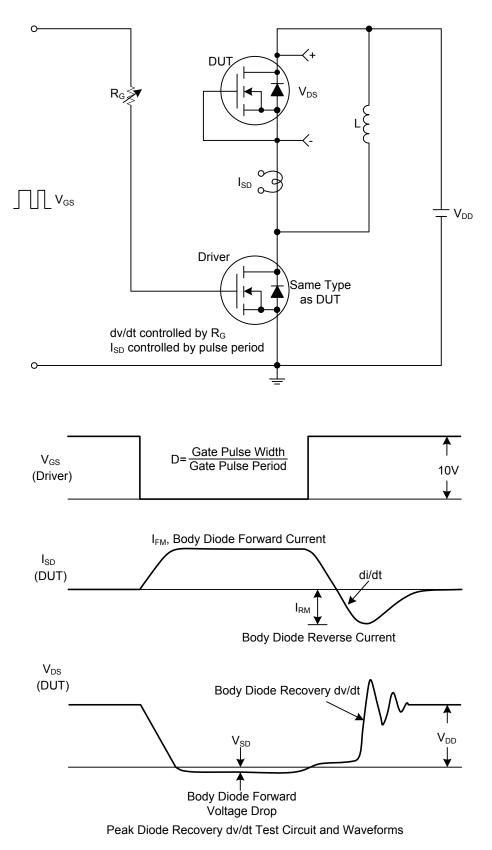
PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	
	STNIBUL	TEST CONDITIONS	IVIIIN		INIAA	UNIT
	D) (		60		1	
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	$V_{GS}=0V, I_D=250\mu A$				V
Drain-Source Leakage Current	DSS	$V_{DS}$ =60V, $V_{GS}$ =0V			25	μA
Gate-Source Leakage Current	I <sub>GSS</sub>	V <sub>DS</sub> =0V ,V <sub>GS</sub> =±20V			±100	nA
ON CHARACTERISTICS				•		
Gate Threshold Voltage	V <sub>GS(TH)</sub>	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> =250µA	1.0		3.0	V
Drain-Source On-State Resistance	R <sub>DS(ON)</sub>	V <sub>GS</sub> =10V, I <sub>D</sub> =14A			42	mΩ
DYNAMIC PARAMETERS	_					
Input Capacitance	CISS			810		рF
Output Capacitance	Coss	V <sub>DS</sub> =25V,V <sub>GS</sub> =0V, f=1.0MHz		260		рF
Reverse Transfer Capacitance	C <sub>RSS</sub>			18		рF
SWITCHING PARAMETERS						
Total Gate Charge (Note 1)	$Q_{G}$	−V <sub>DD</sub> =50V, V <sub>GS</sub> =10V, I <sub>D</sub> =1.3A ,− −I <sub>G</sub> =100μA (Note 1, 2)		86		nC
Gate to Source Charge	$Q_{GS}$			6		nC
Gate to Drain Charge	$Q_{GD}$			5		nC
Turn-ON Delay Time (Note 1)	t <sub>D(ON)</sub>			36		ns
Rise Time	t <sub>R</sub>	$V_{DD}$ =30V, $V_{GS}$ =10V, $I_{D}$ =0.5A,		24		ns
Turn-OFF Delay Time	t <sub>D(OFF)</sub>	$R_G=25\Omega, R_D=1.8\Omega$		366		ns
Fall-Time	t <sub>F</sub>	(Note 1, 2)		64		ns
SOURCE- DRAIN DIODE RATINGS AND CH	ARACTERIS	TICS				
Maximum Body-Diode Continuous Current	ls				28	Α
Maximum Body-Diode Pulsed Current	I <sub>SM</sub>				112	А
Drain-Source Diode Forward Voltage (Note 1)	V <sub>SD</sub>	I <sub>S</sub> =28A, V <sub>GS</sub> =0V			1.3	V
Body Diode Reverse Recovery Time (Note 1)	t <sub>rr</sub>	I <sub>S</sub> =28A, V <sub>GS</sub> =0V		50		ns
Body Diode Reverse Recovery Charge	Q <sub>rr</sub>	dl <sub>F</sub> /dt=100A/µs		0.1	1	μC
			1			

Notes: 1. Pulse Test : Pulse width  $\leq$  300µs, Duty cycle  $\leq$  2%.

2. Essentially independent of operating temperature.

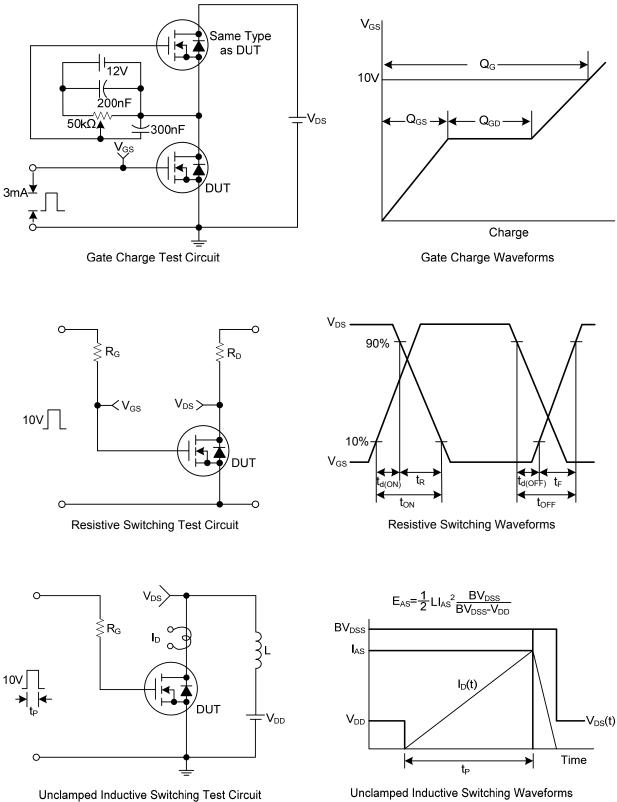


# ■ TEST CIRCUITS AND WAVEFORMS





# **TEST CIRCUITS AND WAVEFORMS**



Unclamped Inductive Switching Waveforms



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